

HT82V732 60mA Audio Power Amp

Features

- Single power supply voltage: 5V
- · Low power consumption
- Low distortion
- · Low clock Jitter sensitivity

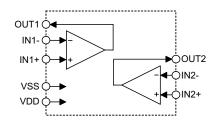
- · High SNR ratio range
- · Wide temperature range
- 8-pin SOP package

General Description

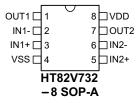
HT82V732 is a class AB stereo earphone driver designed for portable digital audio application. It provides 8-SOP package. Pin assignments and application circuit is compatible with TDA1308 which is suitable for ef-

fective low cost applications. HT82V732 is ideal for portable digital audio equipment, CD ROM/DVD ROM and DISCMAN system.

Block Diagram



Pin Assignment



Pin Description

Pin No.	Pin Name	I/O	Description	
1	OUT1	0	Output	
2	IN1-	I	Inverting input	
3	IN1+	I	Non-inverting input	
4	VSS	_	Negative power supply, ground	
5	IN2+	I	Non-inverting input	
6	IN2-	I	Inverting input	
7	OUT2	0	Output	
8	VDD	_	Positive power supply	

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Electrical Characteristics

 V_{SS} =0V; f_i =1kHz; R_L =32 Ω

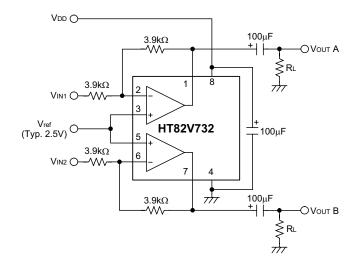
Cumhal	Davamatav		Test Conditions	Min.	т	Mess	I In: !4	
Symbol	Parameter		Conditions	Wiin.	Тур.	Max.	Unit	
Supplies								
	Supply Voltage			_	_	_		
V _{DD}	Single		_	3.0	5.0	6.0	V	
	Dual			1.5	2.5	3		
V _{SS}	Negative Supply Voltage	5V	_	-1.5	-2.5	-3	V	
I _{DD}	Supply Current	5V	No load	_	3	5	mA	
P _{tot}	Total Power Dissipation	5V	No load	_	15	25	mW	
DC Charac	teristics			•	•	•		
V _{I(OS)}	Input Offset Voltage	5V	_	_	10	_	mV	
I _{bias}	Input Bias Current	5V	_	_	10	_	pА	
V _{CM}	Common Mode Voltage	5V	_	0	_	3.5	V	
G _V	Open-loop Voltage Gain	5V	R_L =5k Ω	_	70	_	dB	
Io	Maximum Output Current	5V	(THD+N)/S<0.1%	_	60	_	mA	
Ro	Output Resistance	5V	_	_	0.25	_	Ω	
Vo	Output Voltage swing	5V	R _L =32Ω *	0.75	_	4.25	5	
			R _L =16Ω *	1.5	_	3.5	V	
			R _L =5kΩ *	0.1	_	4.9	1	
PSRR	Power Supply Rejection Ratio	5V	F _i =100Hz; V _{ripple(p-p)} =100mV	_	90	_	dB	
α _{CS}	Channel Separation	5V	_	_	70	_	dB	
C _L	Load Capacitance	5V	_	_	_	200	pF	
AC Charac	teristics					l		
	Total Harmonic Distortion Plus	5V			-70	_	dB	
(THD+N)/S	Noise-to-signal Ratio		V _{O(P-P)} =3.5V **	_	0.03	_	%	
S/N	Signal-to-noise Ratio	5V	_	_	100	_	dB	
f _G	Unity Gain Frequency	5V	Open-loop; R _L =5kΩ	_	5.5	_	MHz	
Po	Maximum Output Power	5V	(THD+N)/S<0.1%		60		mW	
C _i	Input Capacitance	5V	_	_	3	_	pF	
SR	Slew Rate	5V	Unity gain inverting	_	5	_	V/μs	
В	Power Bandwidth	5V	Unity gain inverting		20		kHz	
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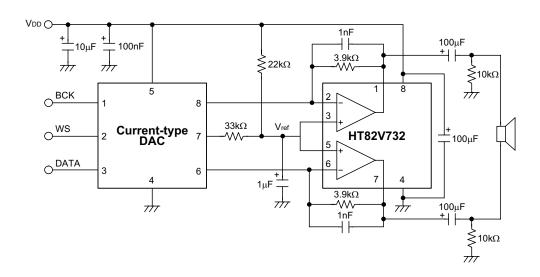
Note: "*" Values are proportional to V_{DD} ; (THD+N)/S<0.1%

"**" V_{DD} =5V, $V_{O(P-P)}$ =3.5V (at odB)



Application Circuits



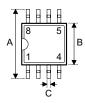


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Package Information

8-pin SOP (150mil) outline dimensions





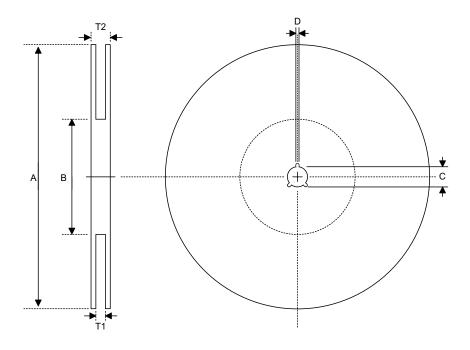


Symbol	Dimensions in mil					
Symbol	Min.	Nom.	Max.			
А	228	_	244			
В	149	_	157			
С	14	_	20			
C'	189	_	197			
D	53	_	69			
E	_	50	_			
F	4	_	10			
G	22	_	28			
Н	4	_	12			
α	0°	_	10°			



Product Tape and Reel Specifications

Reel dimensions

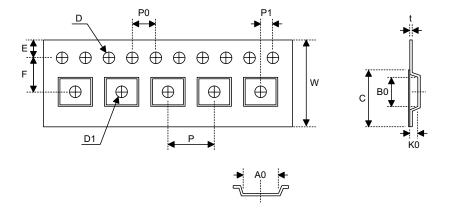


SOP 8N

Symbol	Description	Dimensions in mm
Α	Reel Outer Diameter	330±1.0
В	Reel Inner Diameter	62±1.5
С	Spindle Hole Diameter	13.0+0.5 -0.2
D	Key Slit Width	2.0±0.15
T1	Space Between Flange	12.8+0.3 -0.2
T2	Reel Thickness	18.2±0.2



Carrier tape dimensions



SOP 8N

Symbol	Description	Dimensions in mm
W	Carrier Tape Width	12.0+0.3 -0.1
Р	Cavity Pitch	8.0±0.1
E	Perforation Position	1.75±0.1
F	Cavity to Perforation (Width Direction)	5.5±0.1
D	Perforation Diameter	1.55±0.1
D1	Cavity Hole Diameter	1.5+0.25
P0	Perforation Pitch	4.0±0.1
P1	Cavity to Perforation (Length Direction)	2.0±0.1
A0	Cavity Length	6.4±0.1
В0	Cavity Width	5.20±0.1
K0	Cavity Depth	2.1±0.1
t	Carrier Tape Thickness	0.3±0.05
С	Cover Tape Width	9.3



Holtek Semiconductor Inc. (Headquarters)

No.3, Creation Rd. II, Science-based Industrial Park, Hsinchu, Taiwan

Tel: 886-3-563-1999 Fax: 886-3-563-1189 http://www.holtek.com.tw

Holtek Semiconductor Inc. (Sales Office)

11F, No.576, Sec.7 Chung Hsiao E. Rd., Taipei, Taiwan

Tel: 886-2-2782-9635 Fax: 886-2-2782-9636

Fax: 886-2-2782-7128 (International sales hotline)

Holtek Semiconductor (Shanghai) Inc.

7th Floor, Building 2, No.889, Yi Shan Rd., Shanghai, China

Tel: 021-6485-5560 Fax: 021-6485-0313 http://www.holtek.com.cn

Holtek Semiconductor (Hong Kong) Ltd.

Block A, 3/F, Tin On Industrial Building, 777-779 Cheung Sha Wan Rd., Kowloon, Hong Kong Tel: 852-2-745-8288

Tel: 852-2-745-8288 Fax: 852-2-742-8657

Holmate Semiconductor, Inc.

46712 Fremont Blvd., Fremont, CA 94538

Tel: 510-252-9880 Fax: 510-252-9885 http://www.holmate.com

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